

IXTK82N25P Datasheet



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DiGi Electronics Part Number IXTK82N25P-DG

Manufacturer IXYS

Manufacturer Product Number IXTK82N25P

Description MOSFET N-CH 250V 82A TO264

Detailed Description N-Channel 250 V 82A (Tc) 500W (Tc) Through Hole

TO-264 (IXTK)



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTK82N25P	IXYS
Series:	Product Status:
Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
250 V	82A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	35mOhm @ 41A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 250μA	142 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	4800 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	500W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-264 (IXTK)	TO-264-3, TO-264AA
Base Product Number:	
IXTK82	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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